



15 WATT CLASS B AUDIO AMPLIFIER

BHA-0002

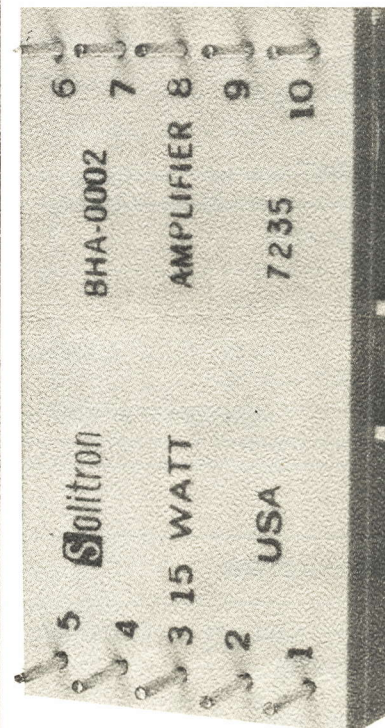
FEATURES:

- Standard Solitron modular package
- Rated output power 15W (RMS) at $T \leq 50^\circ \text{C}$
- Low cost thick film fabrication
- Frequency response: 25 Hz to 20 KHz
- Minimum of external components required

The Solitron BHA-0002 is a Class B Quasi-complementary audio amplifier. It is capable of continuous operation at output powers as high as 15 watts operating into conventional speaker loads. Thick film cermet construction assures uniform performance, optimum reliability and low function cost.

This power microcircuit will produce full output from 350mV input signals—compatible with the great majority of existing preamplifier designs. Useful feedback compensation can be achieved with no external components, but external networks may be added to tailor response to any desired characteristic. External terminals are also provided to permit optional trimming of idle current and crossover characteristics.

The BHA-0002 has been designed for use with stereo/Hi-Fi amplifiers, high quality receivers, public address systems, intercoms and musical instruments. Packaging of the 15 watt amplifier conforms to the standard Solitron modular configuration.



TEST CIRCUIT

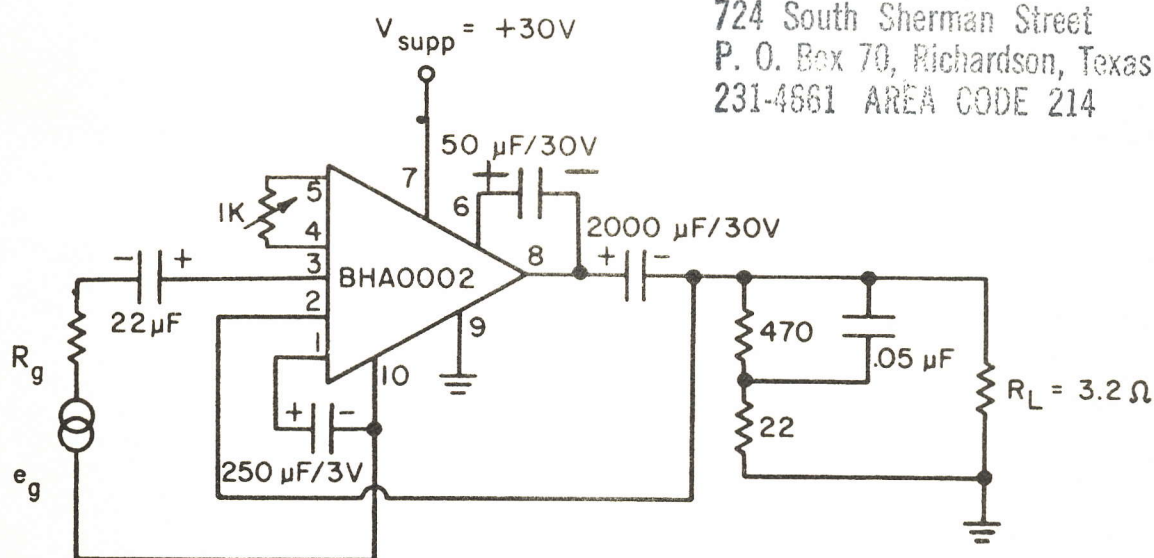


FIGURE 1

P. J. SCANLON COMPANY, INC.
Manufacturers' Representatives
724 South Sherman Street
P. O. Box 70, Richardson, Texas 75080
231-4661 AREA CODE 214



256 OAK TREE ROAD, TAPPAN, N.Y. 10983
PHONE (914) 359-5050/TWX: 710-576-2654/TELEX: 13-7346

TERMINOLOGY

CURRENTS:

I_k — means a current is entering terminal k. (k — 1,2,3, etc.)

$-I_k$ — means a current is leaving terminal k.

VOLTAGES:

V_{n-m} — means a positive voltage is applied to terminal n with terminal m as the reference (n = 1,2,3 etc; m = 1,2,3, etc; n = m)

ELECTRICAL CHARACTERISTICS

ELECTRICAL CHARACTERISTICS AT 30V SUPPLY VOLTAGES AND $T_c \leq 50^\circ\text{C}$ TO BE

MEASURED IN TEST CIRCUIT OF FIGURE 1 (NOTE 1).

PARAMETERS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Power Gain at $P_o = 15\text{ W}$ (RMS) at $f = 1\text{ KHz}$ $G_p = 10 \log \frac{P_o}{P_{in}}$	G_p	55	60		db
Input Voltage for $P_o = 15\text{ W}$ at $f = 1\text{ KHz}$.	V_{3-10}		0.35	0.5	V(RMS)
Frequency Response (-2 db at $P_o = 15\text{ W}$) (See Fig. 3)			25 to 20K		Hz
Quiescent Current (NOTE 2)	I_7		7		mA
Efficiency for $P_o = 15\text{ W}$ ($f = 1\text{ KHz}$)			60		%
Distortion at $f = 1\text{ KHz}$ and $P_o = 15\text{ W}$ (See Figs. 4 & 5)				1	%
Input Impedance	Z_{in}		18K		Ω
Noise Output Relative to $P_o = 15\text{ W}$ (input open, BW = 50 Hz to 10 KHz).	M		-70		db
Thermal Resistance Junction to Case	θ_{J-C}			5	$^\circ\text{C/W}$

NOTE 1: Performance is dependent on the external components that are used in the test circuit.

NOTE 2: Adjust 1k Pot for $I_7 = 7\text{mA}$

MAXIMUM RATINGS

AT $T_C \leq 50^\circ\text{C}$		
Maximum Voltage Pin 7 to 9	V_{7-9}	40.0 Volts
Maximum Current Pin 7	I_7	1.2 Amps
Power Dissipation	P_T	30.0 Watts
Operating Case Temperature	T_C	-30 to $+100^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to $+125^\circ\text{C}$

EQUIVALENT CIRCUIT

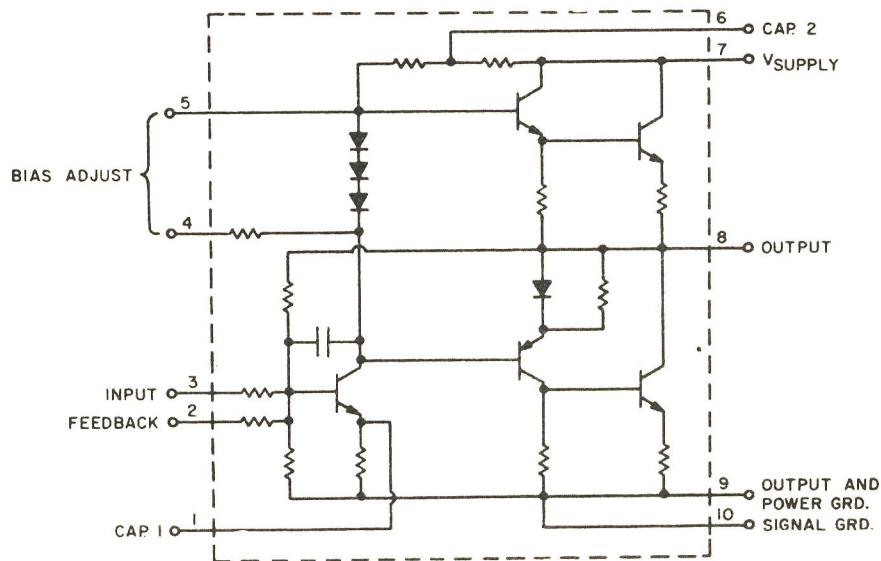
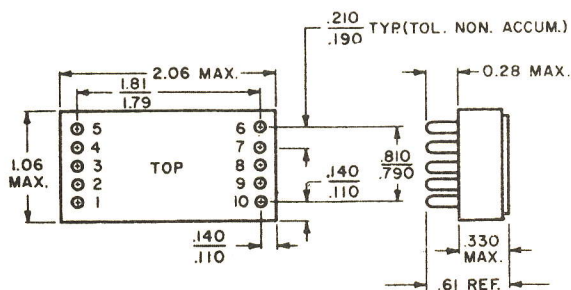


FIGURE 2

STANDARD PACKAGE DESIGN



TAN MOLDED
POLYSULFONE CASE
0.042 DIA.
.038
10 GOLD PLATED
COPPER TERMINALS

CERAMIC SUBSTRATE FORMS THE BOTTOM OF THE PACKAGE AND MUST BE HEATSINKED FOR OUTPUT POWERS GREATER THAN 2W AND AMBIENT TEMPERATURES GREATER THAN 25°C . HEATSINK SHOULD BE EQUIVALENT TO ONE THAT IS USED FOR TRANSISTORS DISSIPATING SIMILAR POWERS. (TYP 6" X 6" X 1/8" ALUMINUM)

TYPICAL FREQUENCY RESPONSE

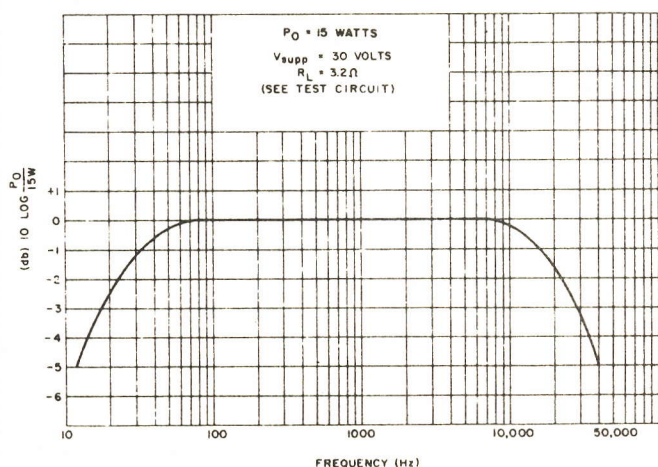


FIGURE 3

TYPICAL THD VS FREQUENCY

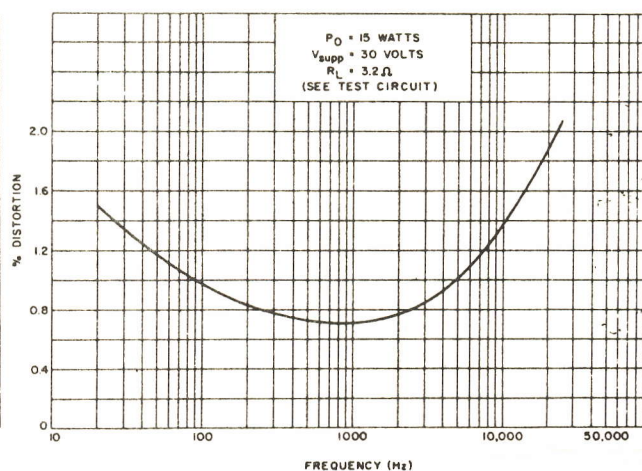


FIGURE 4

TYPICAL THD VS OUTPUT POWER

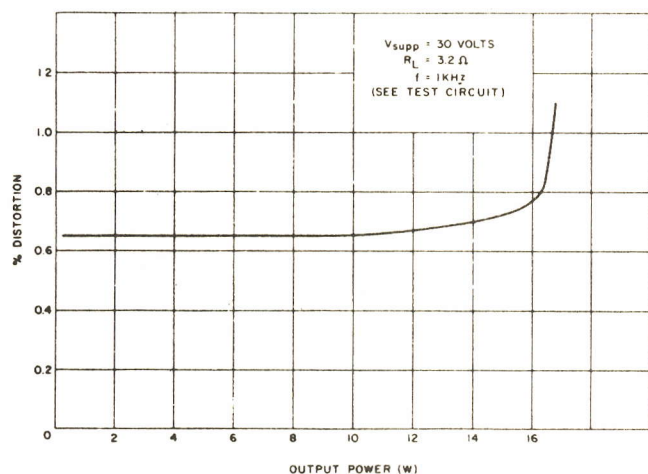


FIGURE 5

TYPICAL OUTPUT POWER VS SUPPLY VOLTAGE

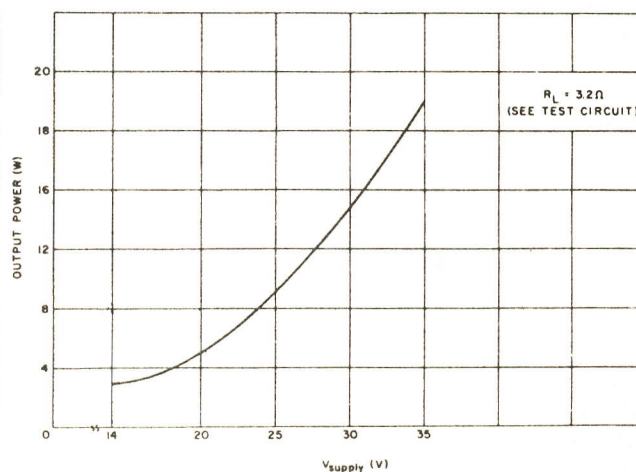


FIGURE 6

TYPICAL OUTPUT POWER VS LOAD RESISTANCE

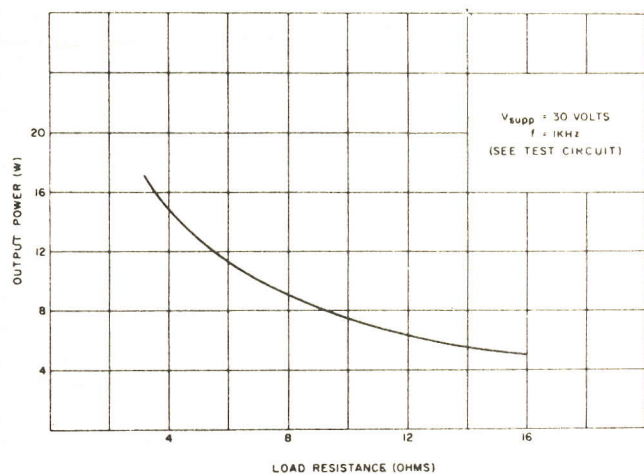


FIGURE 7

OUTPUT POWER VS CASE TEMPERATURE

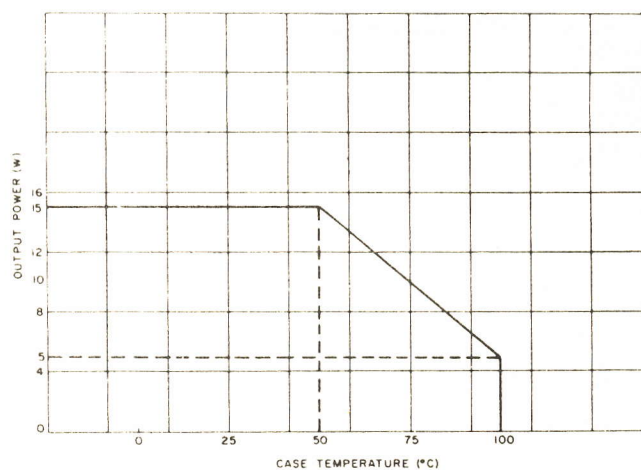


FIGURE 8